



Spec No.: DS30-2002-083 Effective Date: 04/03/2002

Revision: -

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

LITE-ON Technology Corp. / Optoelectronics

No.90, Chien 1 Road, Chung Ho, New Taipei City 23585, Taiwan, R.O.C. Tel: 886-2-2222-6181 Fax: 886-2-2221-1948 / 886-2-2221-0660 http://www.liteon.com/opto

LITEON

LITE-ON ELECTRONICS, INC.

Property of Lite-On Only

FEATURES

- * 2.3 inch (58.42 mm) MATRIX HEIGHT.
- * LOW POWER REQUIREMENT.
- * SINGLE PLANE, WIDE VIEWING ANGLE
- * SOLID STATE RELIABILITY.
- * 8x8 ARRAY WITH X-Y SELECT.
- * COMPATIBLE WITH USASCLL AND EBCDIC CODES.
- * STACKABLE HORIZONTALLY.
- * CATEGORIZED FOR LUMINOUS INTENSITY.

DESCRIPTION

The LTP-2088AKD is a 2.3 inch (58.42 mm) matrix height 8x8 dot matrix display. AlInGaP Hyper Red LED chips, which are made from AlInGaP on a non-transparent GaAs substrate, and has a gray face and white segments.

DEVICE

PART NO.	DESCRIPTION			
AlInGaP Hyper Red	Anode Column			
LTP-2088AKD	Cathode Row			

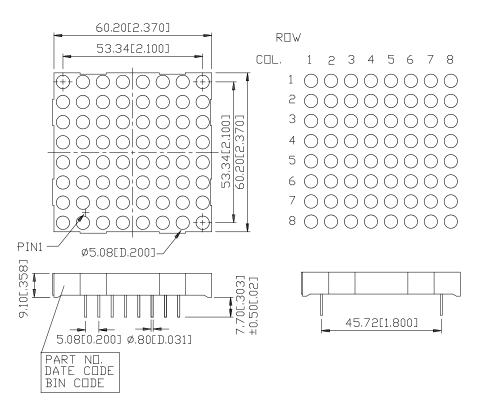
PART NO.: LTP-2088AKD PAGE: 1 of 5

LITEON

LITE-ON ELECTRONICS, INC.

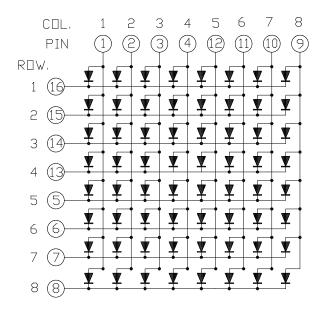
Property of Lite-On Only

PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm (0.01") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



PART NO.: LTP-2088AKD PAGE: 2 of 5

BNS-OD-C131/A4

LITEON LITE-ON ELECTRONICS, INC.

Property of Lite-On Only

PIN CONNECTION

NO.	CONNECTION					
1.	ANODE COL. 1					
2.	ANODE COL. 2					
3.	ANODE COL. 3					
4.	ANODE COL. 4					
5.	CATHODE ROW	5				
6.	CATHODE ROW	6				
7.	CATHODE ROW	7				
8.	CATHODE ROW	8				
9.	ANODE COL. 8					
10.	ANODE COL. 7					
11.	ANODE COL. 6					
12.	ANODE COL. 5					
13.	CATHODE ROW	4				
14.	CATHODE ROW	3				
15.	CATHODE ROW	2				
16.	CATHODE ROW	1				

PART NO.: LTP-2088AKD PAGE: 3 of 5

LITEON LITE-ON ELECTRONICS, INC.

Property of Lite-On Only

ABSOLUTE MAXIMUM RATING AT T_A=25°C

PARAMETER	MAXIMUM RATING	UNIT			
Average Power Dissipation Per Dot	40	mW			
Peak Forward Current Per Dot	90	mA			
Average Forward Current Per Dot	15	mA			
Derating Linear From 25 ^o C Per Dot	0.2	mA/ ⁰ C			
Reverse Voltage Per Dot	5	V			
Operating Temperature Range	-35° C to $+85^{\circ}$ C				
Storage Temperature Range	-35^{0} C to $+85^{0}$ C				
Solder Temperature 1/16 inch Below Seating Plane for 3 Seconds at 260°C					

ELECTRICAL / OPTICAL CHARACTERISTICS AT T_A=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
	Iv	1650	3500	μοσ	1	I _p =32mA
Average Luminous Intensity					μсα	1/16DUTY
Peak Emission Wavelength	λρ		650		nm	I _F =20mA
Spectral Line Half-Width	Δλ		20		nm	I _F =20mA
Dominant Wavelength	λd		639		nm	I _F =20mA
Forward Voltage any Dot	VF		2.1	2.6	V	I _F =20mA
			2.3	2.8	V	IF=80mA
Reverse Current any Dot	Ir			100	μΑ	V _R =5V
Luminous Intensity Matching Ratio	Iv-m			2:1		I _p =32mA
						1/16DUTY

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

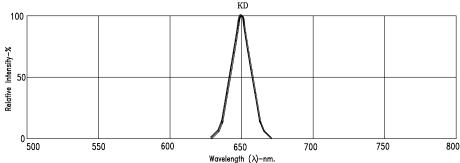
PART NO.: LTP-2088AKD PAGE: 4 of 5

BNS-OD-C131/A4

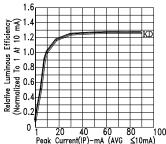
Property of Lite-On Only

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

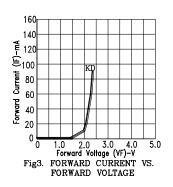
(25°C Ambient Temperature Unless Otherwise Noted)

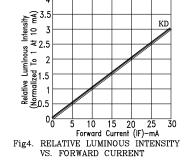


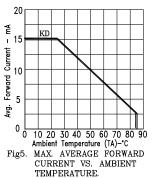
 $\label{eq:wavelength} \mbox{Wavelength } (\lambda) - \mbox{nm}.$ Fig1. RELATIVE INTENSITY VS. WAVELENGTH



0 1 20 40 60 80 100
Peak Current(IP)-mA (AVG ≦10mA)
Fig2. RELATIVE LUMINOUS EFFICIENCY
(LUMINOUS INTENSITY PER UNIT
CURRENT) VS. PEAK CURRENT
(REFRESH RATE 1KHz)







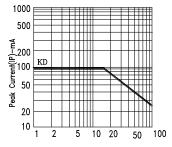


Fig6. MAX. PEAK CURRENT VS.
DUTY CYCLE %
(REFRESH RATE 1KHz)

NOTE : KD=AlInGaP HYPER RED

PART NO.: LTP-2088AKD PAGE: 5 of 5